

SOT223 NPN SILICON PLANAR HIGH PERFORMANCE TRANSISTOR

ISSUE 4- FEBRUARY 1996

FEATURES

- * 25 Volt V_{CE0}
- * 3 Amp continuous current
- * Low saturation voltage
- * Excellent h_{FE} specified up to 6A

勝特力材料 886-3-5753170
勝特力电子(上海) 86-21-34970699
勝特力电子(深圳) 86-755-83298787
[Http://www.100y.com.tw](http://www.100y.com.tw)

COMPLEMENTARY TYPE – FZT749

PARTMARKING DETAIL – FZT649

ABSOLUTE MAXIMUM RATINGS.

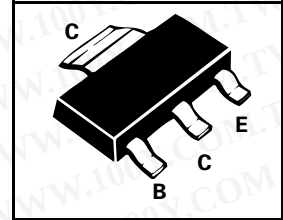
PARAMETER	SYMBOL	VALUE	UNIT
Collector-Base Voltage	V_{CBO}	35	V
Collector-Emitter Voltage	V_{CEO}	25	V
Emitter-Base Voltage	V_{EBO}	5	V
Peak Pulse Current	I_{CM}	8	A
Continuous Collector Current	I_C	3	A
Power Dissipation at $T_{amb}=25^{\circ}C$	P_{tot}	2	W
Operating and Storage Temperature Range	$T_j; T_{stg}$	-55 to +150	$^{\circ}C$

ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^{\circ}C$ unless otherwise stated).

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	CONDITIONS.
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	35			V	$I_C=100\mu A$
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	25			V	$I_C=10mA^*$
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	5			V	$I_E=100\mu A$
Collector Cut-Off Current	I_{CBO}			0.1 10	μA	$V_{CB}=30V$ $V_{CB}=30V, T_{amb}=100^{\circ}C$
Emitter Cut-Off Current	I_{EBO}			0.1	μA	$V_{EB}=4V$
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$		0.12 0.40	0.3 0.6	V	$I_C=1A, I_B=100mA^*$ $I_C=3A, I_B=300mA^*$
Base-Emitter Saturation Voltage	$V_{BE(sat)}$		0.9	1.25	V	$I_C=1A, I_B=100mA^*$
Base-Emitter Turn-On Voltage	$V_{BE(on)}$		0.8	1.0	V	$I_C=1A, V_{CE}=2V^*$
Static Forward Current Transfer Ratio	h_{FE}	70 100 75 15	200 200 150 50	300		$I_C=50mA, V_{CE}=2V^*$ $I_C=1A, V_{CE}=2V^*$ $I_C=2A, V_{CE}=2V^*$ $I_C=6A, V_{CE}=2V^*$
Transition Frequency	f_T	150	240		MHz	$I_C=100mA, V_{CE}=5V$ $f=100MHz$
Output Capacitance	C_{obo}		25	50	pF	$V_{CB}=10V, f=1MHz$
Switching Times	t_{on}		55		ns	$I_C=500mA, V_{CC}=10V$
	t_{off}		300		ns	$I_{B1}=I_{B2}=50mA$

*Measured under pulsed conditions. Pulse Width=300 μs . Duty cycle $\leq 2\%$
Spice parameter data is available upon request for this device

FZT649



FZT649

勝特力材料 886-3-5753170

勝特力电子(上海) 86-21-34970699

勝特力电子(深圳) 86-755-83298787

[Http://www.100y.com.tw](http://www.100y.com.tw)

TYPICAL CHARACTERISTICS

